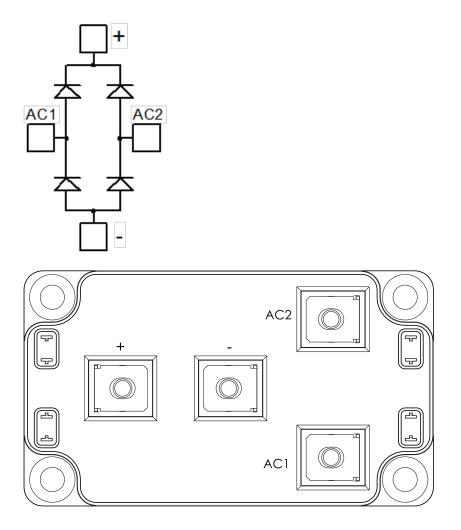


# MSCDC100H120AG SiC Diode Full Bridge Power Module

## **1 Product Overview**

This section shows the product overview for the MSCDC100H120AG device.



All ratings at  $T_i = 25^{\circ}$ C, unless otherwise specified.

Caution: These devices are sensitive to electrostatic discharge. Proper handling procedures should be followed.



### 1.1 Features

The following are key features of the MSCDC100H120AG device:

- Silicon Carbide (SiC) Schottky Diode
  - Zero reverse recovery
  - Zero forward recovery
  - Temperature Independent switching behavior
  - Positive temperature coefficient on VF
- High blocking voltage
- Low stray inductance
- M5 power connectors
- Aluminum nitride (AIN) substrate for improved thermal performance

#### 1.2 Benefits

The following are benefits of the MSCDC100H120AG device:

- Outstanding performance at high-frequency operation
- Low losses
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- RoHS compliant

#### **1.3** Applications

The MSCDC100H120AG device is designed for the following applications:

- Uninterruptible Power Supply (UPS)
- Induction heating
- Welding equipment
- High-speed rectifiers



## 2 Electrical Specifications

This section shows the electrical specifications for the MSCDC100H120AG device.

#### 2.1 Absolute Maximum Ratings

The following table shows the absolute maximum ratings per diode for the MSCDC100H120AG device.

#### Table 1 • Absolute Maximum Ratings

Symbol	Parameter		Maximum Ratings	Unit
Vrrm	Repetitive peak reverse voltage		1200	V
lf	DC forward current	Tc = 100 °C	100	А

The following table shows the thermal and package characteristics of the MSCDC100H120AG.

#### Table 2 • Thermal and Package Characteristics

Symbol	Characteristic			Min	Max	Unit
VISOL	RMS isolation voltage, any terminal to case t =1 minute, 50 Hz/60 Hz			4000		V
TJ	Operating junction temperature range			-40	175	°C
Τιορ	Recommended junction temperature under switching conditions			-40	T <sub>Jmax</sub> -25	
Tstg	Storage temperature range			-40	125	
Tc	Operating case temperature			-40	125	
Torque	Mounting torque	To heatsink	M6	3	5	N.m
		For terminals	M5	2	3.5	
Wt	Package weight				300	g

## 2.2 Electrical Performance

The following table shows the electrical characteristics per diode of the MSCDC100H120AG.

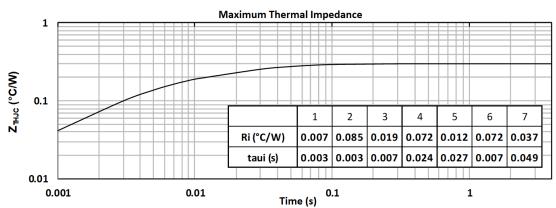
Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
VF	Diode forward voltage	IF = 100 A	T <sub>j</sub> = 25 °C		1.5	1.8	V
			T <sub>j</sub> = 175 °C		2.1		-
Irm	Reverse leakage current	V <sub>R</sub> = 1200 V	T <sub>j</sub> = 25 °C		30	400	μΑ
			T <sub>j</sub> = 175 °C		500		-
Qc	Total capacitive charge	V <sub>R</sub> = 600 V			448		nC
С	Total capacitance	f = 1 MHz, V <sub>R</sub> = 400 V		492		pF	
		f = 1 MHz, V <sub>R</sub> = 8	300 V		364		-
RthJC	Junction to case thermal resistan	се				0.304	°C/W

#### Table 3 • Electrical Characteristics Per Diode



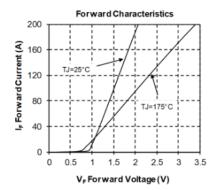
## 2.3 Performance Curves

This section shows the typical performance curves for the MSCDC100H120AG device.

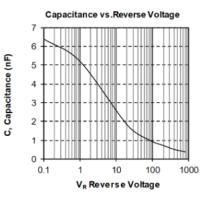


#### Figure 1 • Maximum Transient Thermal Impedance





#### Figure 3 • Capacitance vs. Reverse Voltage





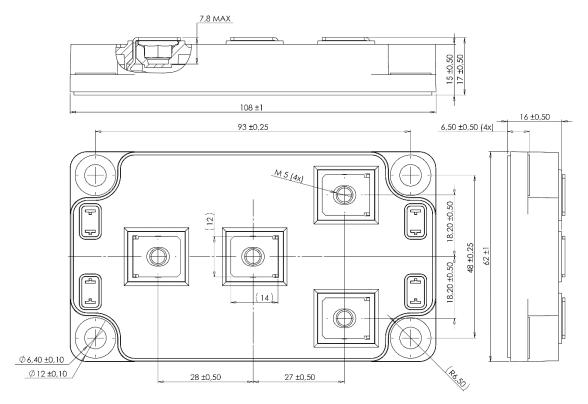
# 3 Package Specifications

This section shows the package specifications for the MSCDC100H120AG device.

### 3.1 Package Outline Drawing

This section shows the package outline drawing of the MSCDC100H120AG device. The dimensions in the following figure are in millimeters.

#### Figure 4 • Package Outline Drawing







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MSCC-0344-DS-01000-1.0-0519 | May 2019 | Final

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